Vishay General Semiconductor

## **Dual Common-Cathode Schottky Rectifier**



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| PRIMARY CHARACTERISTICS |            |  |  |  |  |
|-------------------------|------------|--|--|--|--|
| I <sub>F(AV)</sub>      | 2 x 10 A   |  |  |  |  |
| V <sub>RRM</sub>        | 50 V, 60 V |  |  |  |  |
| I <sub>FSM</sub>        | 150 A      |  |  |  |  |
| $V_F$ at $I_F$ = 10 A   | 0.570 V    |  |  |  |  |
| T <sub>J</sub> max.     | 150 °C     |  |  |  |  |

### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, OR-ing diodes, DC/DC converters or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)                       |              |                    |              |         |      |  |
|--|--------------|--------------------|--------------|---------|------|--|
| PARAMETER  |              | SYMBOL             | MI2050C      | MI2060C | UNIT |  |
| Maximum repetitive peak reverse voltage  |              | V <sub>RRM</sub>   | 50           | 60      | V    |  |
| Maximum average forward rectified current (Fig.1)  | total device | <b>I</b> =44.6     | 20           |         | A    |  |
|  | per diode    | I <sub>F(AV)</sub> | 10           |         |      |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode |              | I <sub>FSM</sub>   | 150          |         | А    |  |
| Peak repetitive reverse current per leg at $t_p$ = 2 µs, 1 kHz per diode                     |              | I <sub>RRM</sub>   | 0.5          |         | А    |  |
| Voltage rate of change (rated V <sub>R</sub> )   |              | dV/dt              | 10 000       |         | V/µs |  |
| Operating junction temperature range   |              | TJ                 | - 65 to +150 |         | °C   |  |
| Storage temperature range  |              | T <sub>STG</sub>   | - 65 to +175 |         | °C   |  |

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ROHS COMPLIANT



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| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted) |                               |                       |                         |       |      |      |  |
|---|-------------------------------|-----------------------|-------------------------|-------|------|------|--|
| PARAMETER   | SYMBOL                        | TEST CONDITIONS       |                         | TYP.  | MAX. | UNIT |  |
| Maximum instantaneous forward voltage per diode                           | V <sub>F</sub> <sup>(1)</sup> | I <sub>F</sub> = 5 A  | T <sub>J</sub> = 25 °C  | 0.554 | -    | V    |  |
|   |                               | I <sub>F</sub> = 10 A | T <sub>J</sub> = 125 °C | 0.649 | 0.74 |      |  |
|   |                               | I <sub>F</sub> = 5 A  | T <sub>J</sub> = 25 °C  | 0.484 | -    |      |  |
|   |                               | I <sub>F</sub> = 10 A | T <sub>J</sub> = 125 °C | 0.570 | 0.62 |      |  |
| Reverse current per diode   | I <sub>R</sub> <sup>(2)</sup> | rated V <sub>R</sub>  | T <sub>J</sub> = 25 °C  | 15    | 150  | μA   |  |
|   |                               |                       | T <sub>J</sub> = 100 °C | 10.8  | 25   | mA   |  |
| Typical junction capacitance  | CJ                            | 4.0 V, 1 MHz          |                         | 300   | -    | pF   |  |

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                     |         |         |      |  |  |
|--|---------------------|---------|---------|------|--|--|
| PARAMETER  | SYMBOL              | MI2050C | MI2060C | UNIT |  |  |
| Typical thermal resistance per diode   | $R_{	ext{	heta}JC}$ | 2.      | °C/W    |      |  |  |

| ORDERING INFORMATION (Example) |               |                              |    |               |               |  |
|--------------------------------|---------------|------------------------------|----|---------------|---------------|--|
| PACKAGE                        | PREFERRED P/N | UNIT WEIGHT (g) PACKAGE CODE |    | BASE QUANTITY | DELIVERY MODE |  |
| TO-262AA                       | MI2060C-E3/4W | 1.456                        | 4W | 50/tube       | Tube          |  |

#### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

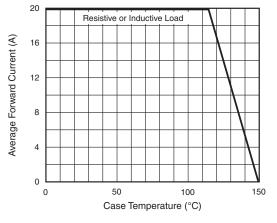


Fig. 1 - Forward Current Derating Curve

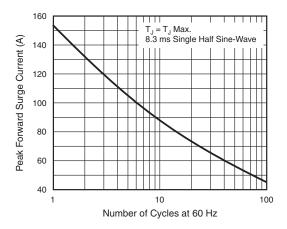


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge pCurrent Per Diode



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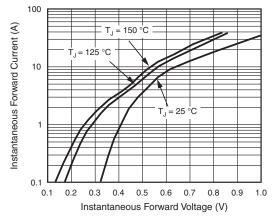


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

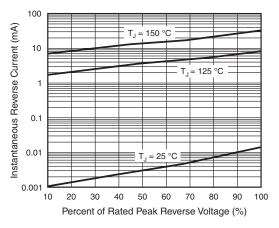


Fig. 4 - Typical Reverse Characteristics Per Diode

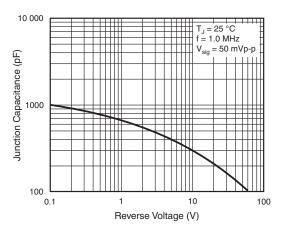


Fig. 5 - Typical Junction Capacitance Per Diode

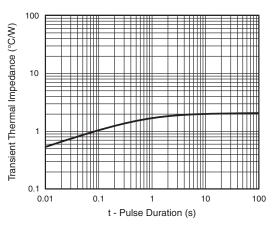
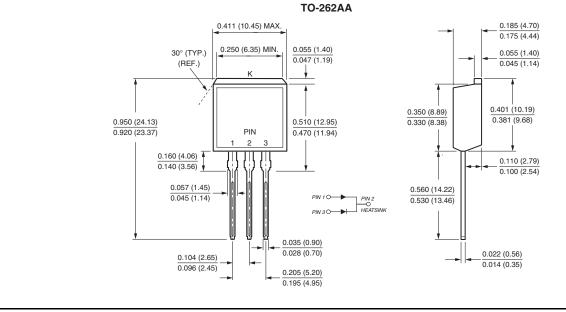


Fig. 6 - Typical Transient Thermal Impedance Per Diode



### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

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For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



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